NSN 5961-00-504-8587

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-504-8587 **Inclosure Material:** Glass **Overall Length:** 0.255 inches **Terminal Length:** 1.000 inches **Overall Width:** 0.265 inches **Mounting Method: Terminal Terminal Circle Diameter:** 0.020 inches **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 180.0 working peak reverse voltage **Current Rating Per Characteristic:** 35.00 milliamperes collector current, dc **Power Rating Per Characteristic:** 150.0 milliwatts small-signal input power, common-collector **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius ambient air **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig:

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